

Product Summary

- Continuous Drain Source Voltage 60V
- On-state Resistance 200mΩ
- Nominal Load Current ($V_{IN} = 5V$) 2.0A
- Clamping Energy 490mJ

Description

The ZXMS6005DGQ-13 is a self protected low side IntelliFET™ MOSFET with logic level input. It integrates over-temperature, over-current, over-voltage (active clamp) and ESD protected logic level functionality. The ZXMS6005DGQ-13 is ideal as a general purpose switch driven from 3.3V or 5V microcontrollers in harsh environments where standard MOSFETs are not rugged enough.

Applications

- Lamp Driver
- Motor Driver
- Relay Driver
- Solenoid Driver

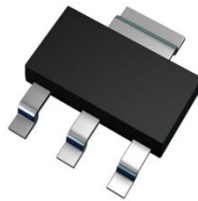
Features and Benefits

- Compact High Power Dissipation Package
- Low Input Current
- Logic Level Input (3.3V and 5V)
- Short Circuit Protection with Auto Restart
- Over Voltage Protection (Active Clamp)
- Thermal Shutdown with Auto Restart
- Over-current Protection
- Input Protection (ESD)
- High Continuous Current Rating
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

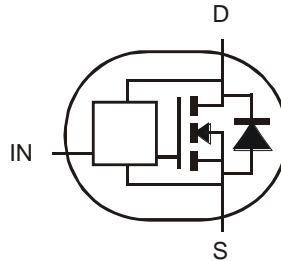
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish e3
- Weight: 0.12 grams (Approximate)

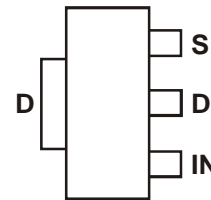
SOT223 (Type DN)



Top View



Device Symbol



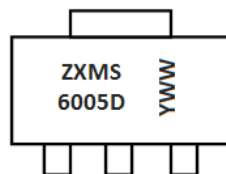
Top View
Pin Out

Ordering Information (Note 5)

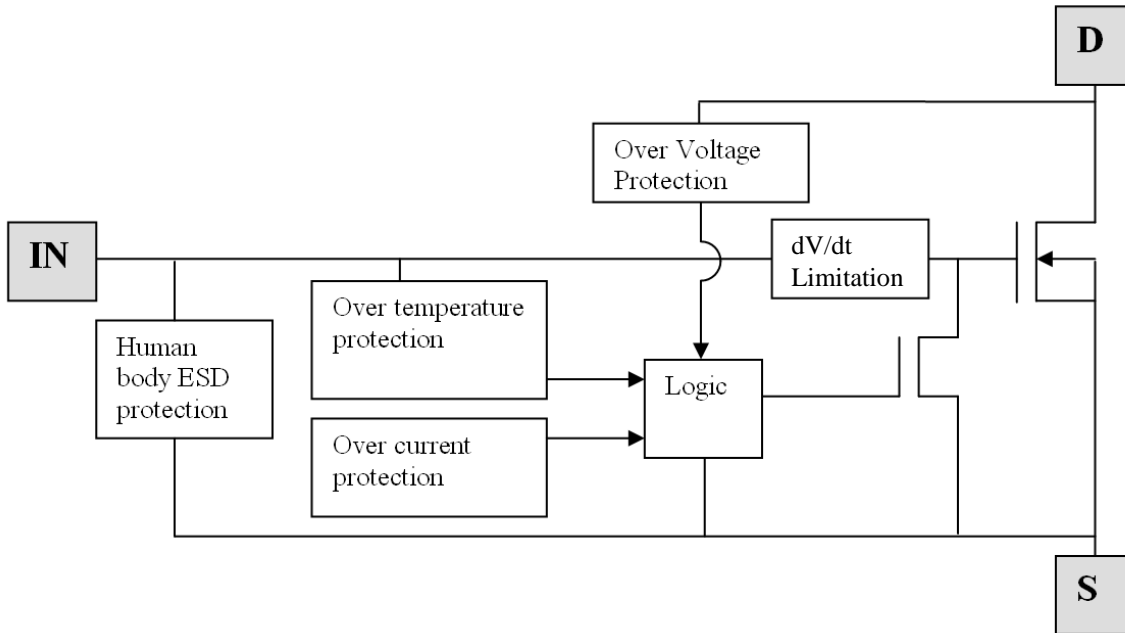
Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZXMS6005DGQ-13	ZXMS6005D	13	12	2,500 Units

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Please refer to <https://www.diodes.com/quality/>.
 5. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



ZXMS6005D = Product Type Marking Code
 YWW = Date Code Marking
 Y or \bar{Y} = Last Digit of Year (ex: 8 = 2018)
 WW or \bar{W} = Week Code (01 to 53)

Functional Block Diagram

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Continuous Drain-Source Voltage	V _{DS}	60	V
Drain-Source Voltage for Short Circuit Protection	V _{DS(SC)}	24	V
Continuous Input Voltage	V _{IN}	-0.5 to +6	V
Continuous Input Current @ -0.2V ≤ V _{IN} ≤ 6V	I _{IN}	No limit	mA
Continuous Input Current @ V _{IN} < -0.2V or V _{IN} > 6V	I _{IN}	I _{IN} ≤ 2	mA
Pulsed Drain Current @ V _{IN} = 3.3V	I _{DM}	5	A
Pulsed Drain Current @ V _{IN} = 5V	I _{DM}	6	A
Continuous Source Current (Body Diode) (Note 6)	I _S	2.5	A
Pulsed Source Current (Body Diode)	I _{SM}	10	A
Unclamped Single Pulse Inductive Energy, T _J = +25°C, I _D = 0.5A, V _{DD} = 24V	E _{AS}	490	mJ
Electrostatic Discharge (Human Body Model)	V _{ESD}	4000	V
Charged Device Model	V _{CDM}	1000	V

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation at T _A = +25°C (Note 6)	P _D	1.32	W
Linear Derating Factor		10.5	mW/°C
Power Dissipation at T _A = +25°C (Note 7)	P _D	1.69	W
Linear Derating Factor		13.5	mW/°C
Thermal Resistance, Junction to Ambient (Note 6)	R _{θJA}	94.8	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	R _{θJA}	74	°C/W
Thermal Resistance, Junction to Case (Note 8)	R _{θJC}	9.3	°C/W
Operating Temperature Range	T _J	-40 to +150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

- Notes:
6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 7. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 8. Thermal resistance between junction and the mounting surfaces of drain and source pins.

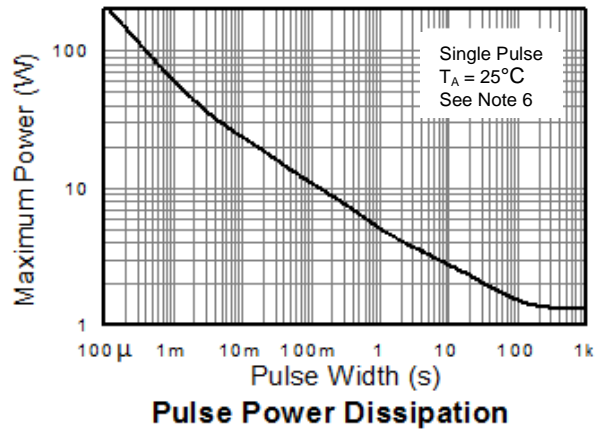
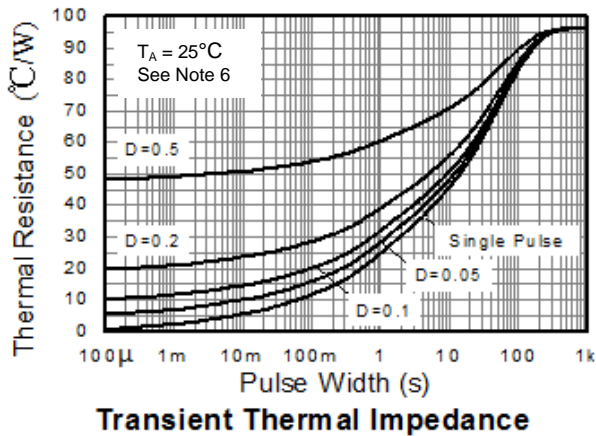
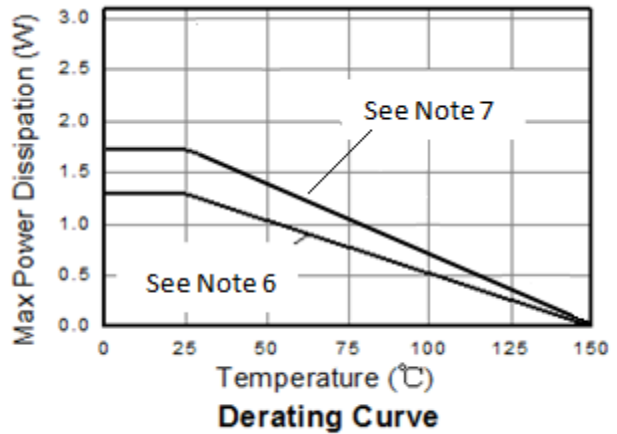
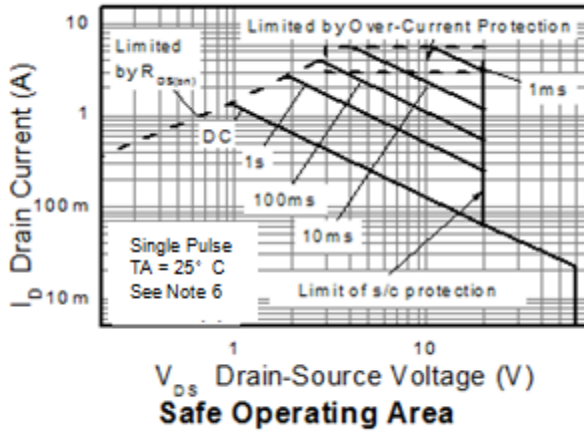
Recommended Operating Conditions

The ZXMS6005DGQ-13 is optimized for use with μ C operating from 3.3V and 5V supplies.

Characteristic	Symbol	Min	Max	Unit
Input Voltage Range	V_{IN}	0	5.5	V
Ambient Temperature Range	T_A	-40	+125	$^{\circ}$ C
High Level Input Voltage for MOSFET to be on	V_{IH}	3	5.5	V
Low Level Input Voltage for MOSFET to be off	V_{IL}	0	0.7	V
Peripheral Supply Voltage (voltage to which load is referred)	V_P	0	24	V

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Thermal Characteristics



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

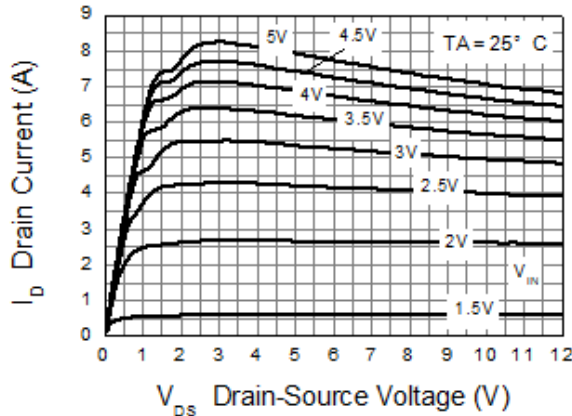
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Static Characteristics						
Drain-Source Clamp Voltage	V _{DS(AZ)}	60	65	70	V	I _D = 10mA
Off State Drain Current	I _{DSS}	—	—	1	μA	V _{DS} = 12V, V _{IN} = 0V
		—	—	2		V _{DS} = 36V, V _{IN} = 0V
Input Threshold Voltage	V _{IN(TH)}	0.7	1.2	1.5	V	V _{DS} = V _{GS} , I _D = 1mA
Input Current	I _{IN}	—	60	100	μA	V _{IN} = 3V
		—	120	200		V _{IN} = 5V
Input Current While Over Temperature Active	—	—	—	300	μA	V _{IN} = 5V
Static Drain-Source On-State Resistance	R _{DS(ON)}	—	170	250	mΩ	V _{IN} = 3V, I _D = 1A
		—	150	200		V _{IN} = 5V, I _D = 1A
Continuous Drain Current (Note 6)	I _D	1.4	—	—	A	V _{IN} = 3V, T _A = +25°C
		1.6	—	—		V _{IN} = 5V, T _A = +25°C
Continuous Drain Current (Note 7)		1.9	—	—		V _{IN} = 3V, T _A = +25°C
		2.0	—	—		V _{IN} = 5V, T _A = +25°C
Current Limit (Note 9)	I _{D(LIM)}	2.2	5	—	A	V _{IN} = 3V
		3.3	7	—		V _{IN} = 5V
Dynamic Characteristics						
Turn On Delay Time	t _{D(ON)}	—	6	—	μs	V _{DD} = 12V, I _D = 1A, V _{GS} = 5V
Rise Time	t _R	—	14	—		
Turn Off Delay Time	t _{D(OFF)}	—	34	—		
Fall Time	t _F	—	19	—		
Over-Temperature Protection						
Thermal Overload Trip Temperature (Note 10)	T _{JT}	+150	+175	—	°C	—
Thermal Hysteresis (Note 10)	f _t	—	+10	—	°C	—

Notes: 9. The drain current is restricted only when the device is in saturation (see graph 'Typical Output Characteristic'). This allows the device to be used in the fully on state without interference from the current limit. The device is fully protected at all drain currents, as the low power dissipation generated outside saturation makes current limit unnecessary.

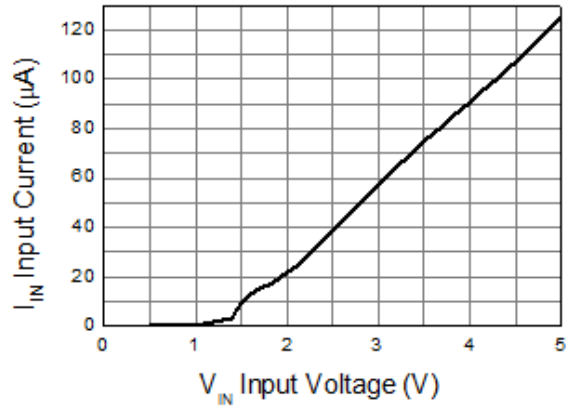
10. Over-temperature protection is designed to prevent device destruction under fault conditions. Fault conditions are considered as "outside" normal operating range, so this part is not designed to withstand over-temperature for extended periods.

Typical Characteristics

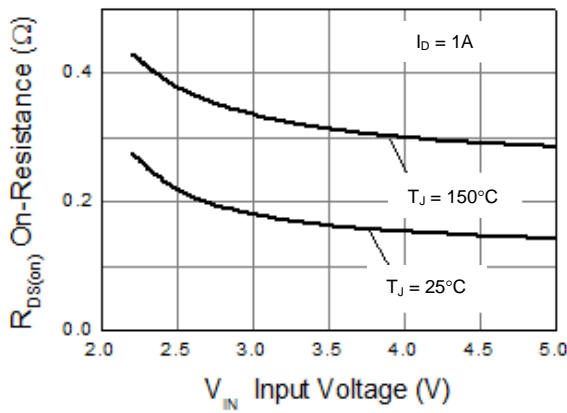
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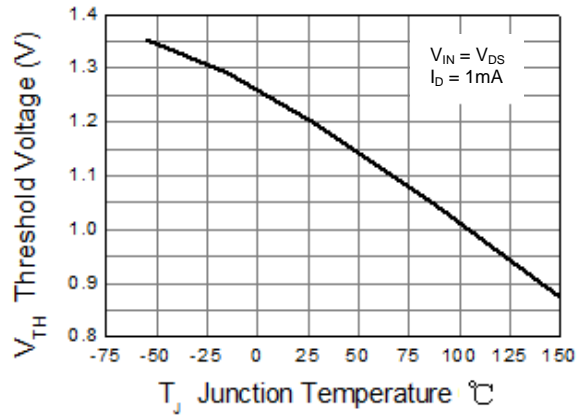
Typical Output Characteristic



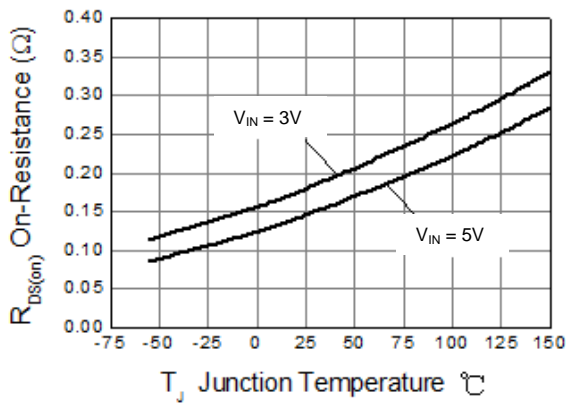
Input Current vs Input Voltage



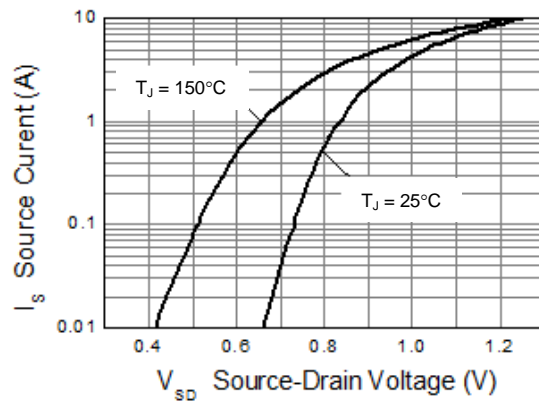
On-Resistance vs Input Voltage



Threshold Voltage vs Temperature



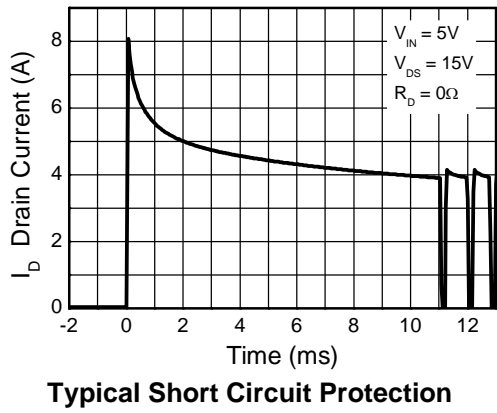
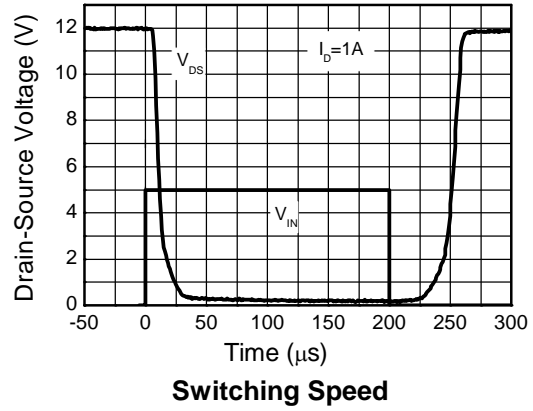
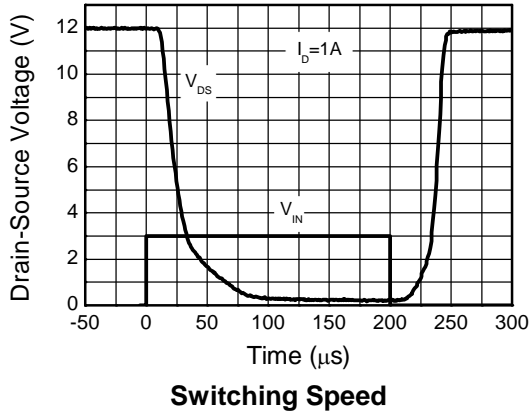
On-Resistance vs Temperature



Reverse Diode Characteristic

Typical Characteristics (Cont.)

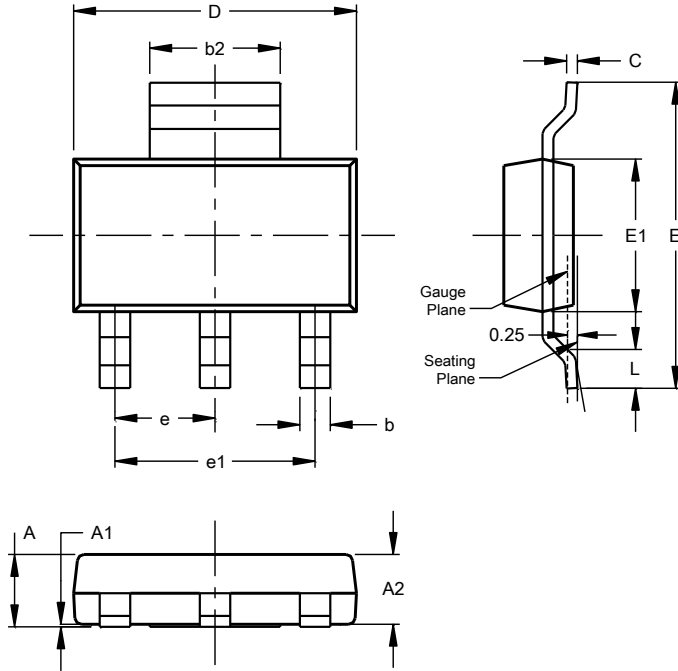
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Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)



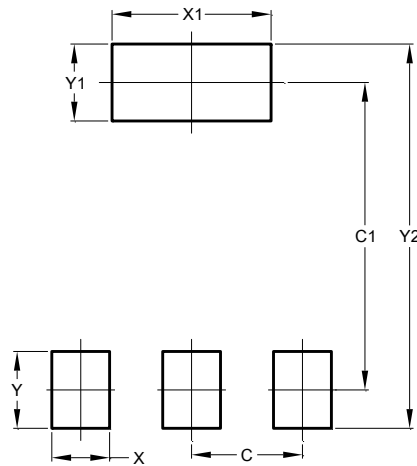
SOT223 (Type DN)			
Dim	Min	Max	Typ
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

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Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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